74AVC4T3144-Q100

4-bit dual-supply buffer/level translator; 3-state

Rev. 1 — 15 November 2019 Product data sheet

1. General description

The 74AVC4T3144-Q100 is a 4-bit, dual-supply level translating buffer with 3-state outputs. It features four data inputs (An and B4), four data outputs (YBn and YA4), and an output enable input ($\overline{OE}$). The device is configured to translate three inputs from $V_{CC(A)}$ to $V_{CC(B)}$ and one input from $V_{CC(B)}$ to $V_{CC(A)}$. $\overline{OE}$, An and YA4 are referenced to $V_{CC(A)}$ and YBn and B4 are referenced to $V_{CC(B)}$. A HIGH on $\overline{OE}$ causes the outputs to assume a high-impedance OFF-state.

The device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables outputs, preventing any damaging backflow current through the device when it is powered down. In suspend mode when either $V_{CC(A)}$ or $V_{CC(B)}$ are at GND level, all outputs are in the high-impedance OFF-state.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range:
  - $V_{CC(A)}$: 0.8 V to 3.6 V
  - $V_{CC(B)}$: 0.8 V to 3.6 V
- Complies with JEDEC standards:
  - JESD8-12 (0.8 V to 1.3 V)
  - JESD8-11 (0.9 V to 1.65 V)
  - JESD8-7 (1.2 V to 1.95 V)
  - JESD8-5 (1.8 V to 2.7 V)
  - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - MIL-STD-883, method 3015 Class 3B exceeds 8000 V
  - HBM JESD22-A114E Class 3B exceeds 8000 V
- Maximum data rates:
  - 380 Mbit/s (≥ 1.8 V to 3.3 V translation)
  - 200 Mbit/s (≥ 1.1 V to 3.3 V translation)
  - 200 Mbit/s (≥ 1.1 V to 2.5 V translation)
  - 200 Mbit/s (≥ 1.1 V to 1.8 V translation)
  - 150 Mbit/s (≥ 1.1 V to 1.5 V translation)
  - 100 Mbit/s (≥ 1.1 V to 1.2 V translation)
- Suspend mode
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- I_{OFF} circuitry provides partial Power-down mode operation

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3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AVC4T3144GU12-Q100	-40 °C to +125 °C	XQFN12	plastic, extremely thin quad flat package; no leads; 12 terminals; body 1.70 x 2.0 x 0.50 mm	SOT1174-1

4. Marking

Table 2. Marking codes

Type number	Marking code
74AVC4T3144GU12-Q100	Bd

5. Functional diagram

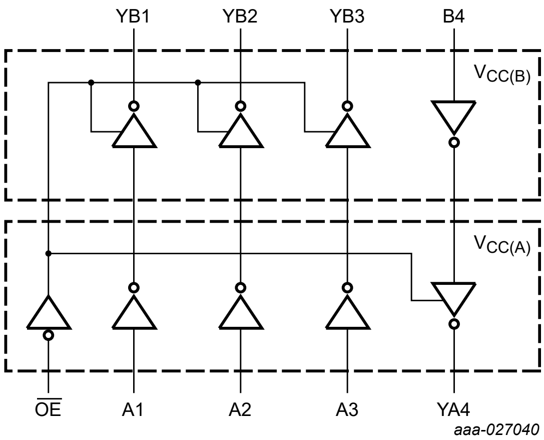


Fig. 1. Logic symbol

6. Pinning information

6.1. Pinning

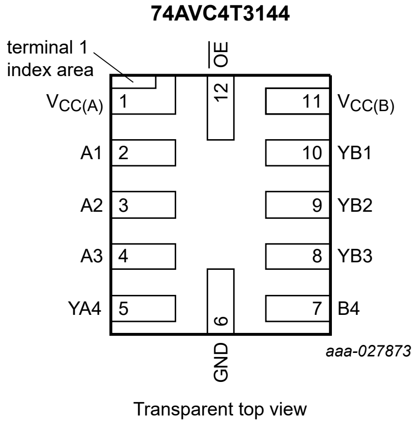


Fig. 2. Pin configuration XQFN12 (SOT1174-1)

6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
$V_{CC(A)}$	1	supply voltage A (A1, A2, A3, YA4 and $\overline{OE}$ pins are referenced to $V_{CC(A)}$)
A1, A2, A3, B4	2, 3, 4, 7	data input
GND	6	ground (0 V)
YB1, YB2, YB3, YA4	10, 9, 8, 5	data output
$\overline{OE}$	12	output enable input (active LOW)
$V_{CC(B)}$	11	supply voltage B (YB1, YB2, YB3 and B4 pins are referenced to $V_{CC(B)}$)

7. Functional description

Table 4. Function table [1][2]

Supply voltage	Input	Input	Output
$V_{CC(A)}$, $V_{CC(B)}$	$\overline{OE}$	An, B4	YBn, YA4
0.8 V to 3.6 V	L	L	L
0.8 V to 3.6 V	L	H	H
0.8 V to 3.6 V	H	X	Z
GND[3]	X	Z	Z

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.
[2] The A1, A2, A3, YA4 and $\overline{OE}$ pins are referenced to $V_{CC(A)}$; The YB1, YB2, YB3 and B4 pins are referenced to $V_{CC(B)}$.
[3] If at least one of $V_{CC(A)}$ or $V_{CC(B)}$ is at GND level, the device goes into suspend mode.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CC(A)}$	supply voltage A			-0.5	+4.6	V
$V_{CC(B)}$	supply voltage B			-0.5	+4.6	V
I_{IK}	input clamping current	$V_I < 0$ V		-50	-	mA
V_I	input voltage		[1]	-0.5	+4.6	V
I_{OK}	output clamping current	$V_O < 0$ V		-50	-	mA
V_O	output voltage	Active mode	[1][2][3]	-0.5	V_{CCO} + 0.5	V
		Suspend or 3-state mode	[1]	-0.5	+4.6	V
I_O	output current	V_O = 0 V to V_{CCO}	[2]	-	±50	mA
I_{CC}	supply current	$I_{CC(A)}$ or $I_{CC(B)}$		-	100	mA
I_{GND}	ground current			-100	-	mA
T_{stg}	storage temperature			-65	+150	°C
P_{tot}	total power dissipation	T_{amb} = -40 °C to +125 °C		-	250	mW

[1] The minimum input voltage ratings and output voltage ratings may be exceeded if the input and output current ratings are observed.
[2] V_{CCO} is the supply voltage associated with the output port.
[3] V_{CCO} + 0.5 V should not exceed 4.6 V.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CC(A)}$	supply voltage A			0.8	3.6	V
$V_{CC(B)}$	supply voltage B			0.8	3.6	V
V_I	input voltage			0	3.6	V
V_O	output voltage	Active mode	[1]	0	V_{CCO}	V
		Suspend or 3-state mode		0	3.6	V
T_{amb}	ambient temperature			-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V_{CCI} =0.8 V to 3.6 V	[2]	-	10	ns/V

[1] V_{CCO} is the supply voltage associated with the output port.
[2] V_{CCI} is the supply voltage associated with the input port.

10. Static characteristics

Table 7. Typical static characteristics at T_{amb} = 25 °C[1][2]

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_O = -1.5 mA; $V_{CC(A)} = V_{CC(B)}$ = 0.8 V	-	0.69	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_O = 1.5 mA; $V_{CC(A)} = V_{CC(B)}$ = 0.8 V	-	0.07	-	V
I_I	input leakage current	$\overline{OE}$ input; V_I = 0 V or 3.6 V; $V_{CC(A)} = V_{CC(B)}$ = 0.8 V to 3.6 V	-	±0.025	±0.25	μA
I_{OZ}	OFF-state output current	A or B port; V_O = 0 V or V_{CCO}; $V_{CC(A)} = V_{CC(B)}$ = 3.6 V	-	±0.5	±2.5	μA
		suspend mode A port; V_O = 0 V or V_{CCO}; $V_{CC(A)}$ = 3.6 V; $V_{CC(B)}$ = 0 V	-	±0.5	±2.5	μA
		suspend mode B port; V_O = 0 V or V_{CCO}; $V_{CC(A)}$ = 0 V; $V_{CC(B)}$ = 3.6 V	-	±0.5	±2.5	μA
I_{OFF}	power-off leakage current	A port; V_I or V_O = 0 V to 3.6 V; $V_{CC(A)}$ = 0 V; $V_{CC(B)}$ = 0.8 V to 3.6 V	-	±0.1	±1	μA
		B port; V_I or V_O = 0 V to 3.6 V; $V_{CC(B)}$ = 0 V; $V_{CC(A)}$ = 0.8 V to 3.6 V	-	±0.1	±1	μA
C_I	input capacitance	$\overline{OE}$ input; V_I = 0 V or 3.3 V; $V_{CC(A)} = V_{CC(B)}$ = 3.3 V	-	2.0	-	pF
$C_{I/O}$	input/output capacitance	A and B port; V_O = 3.3 V or 0 V; $V_{CC(A)} = V_{CC(B)}$ = 3.3 V	-	4.0	-	pF

[1] V_{CCO} is the supply voltage associated with the output port.
[2] V_{CCI} is the supply voltage associated with the data input port.

Table 8. Static characteristics[1][2]

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Max	Min	Max	
V_{IH}	HIGH-level input voltage	data input					
		V_{CCI} = 0.8 V	$0.70V_{CCI}$	-	$0.70V_{CCI}$	-	V
		V_{CCI} = 1.1 V to 1.95 V	$0.65V_{CCI}$	-	$0.65V_{CCI}$	-	V
		V_{CCI} = 2.3 V to 2.7 V	1.6	-	1.6	-	V
		V_{CCI} = 3.0 V to 3.6 V	2	-	2	-	V
		$\overline{OE}$ input					
		$V_{CC(A)}$ = 0.8 V	$0.70V_{CC(A)}$	-	$0.70V_{CC(A)}$	-	V
		$V_{CC(A)}$ = 1.1 V to 1.95 V	$0.65V_{CC(A)}$	-	$0.65V_{CC(A)}$	-	V
		$V_{CC(A)}$ = 2.3 V to 2.7 V	1.6	-	1.6	-	V
		$V_{CC(A)}$ = 3.0 V to 3.6 V	2	-	2	-	V

Symbol	Parameter	Conditions	-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Max	Min	Max	
V_{IL}	LOW-level input voltage	data input					
		V_{CCI} = 0.8 V	-	$0.30V_{CCI}$	-	$0.30V_{CCI}$	V
		V_{CCI} = 1.1 V to 1.95 V	-	$0.35V_{CCI}$	-	$0.35V_{CCI}$	V
		V_{CCI} = 2.3 V to 2.7 V	-	0.7	-	0.7	V
		V_{CCI} = 3.0 V to 3.6 V	-	0.8	-	0.8	V
		$\overline{OE}$ input					
		$V_{CC(A)}$ = 0.8 V	-	$0.30V_{CC(A)}$	-	$0.30V_{CC(A)}$	V
		$V_{CC(A)}$ = 1.1 V to 1.95 V	-	$0.35V_{CC(A)}$	-	$0.35V_{CC(A)}$	V
		$V_{CC(A)}$ = 2.3 V to 2.7 V	-	0.7	-	0.7	V
		$V_{CC(A)}$ = 3.0 V to 3.6 V	-	0.8	-	0.8	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}					
		I_O = -100 µA; $V_{CC(A)} = V_{CC(B)}$ = 0.8 V to 3.6 V	V_{CCO} - 0.1	-	V_{CCO} - 0.1	-	V
		I_O = -3 mA; $V_{CC(A)} = V_{CC(B)}$ = 1.1 V	0.85	-	0.85	-	V
		I_O = -6 mA; $V_{CC(A)} = V_{CC(B)}$ = 1.4 V	1.05	-	1.05	-	V
		I_O = -8 mA; $V_{CC(A)} = V_{CC(B)}$ = 1.65 V	1.2	-	1.2	-	V
		I_O = -9 mA; $V_{CC(A)} = V_{CC(B)}$ = 2.3 V	1.75	-	1.75	-	V
		I_O = -12 mA; $V_{CC(A)} = V_{CC(B)}$ = 3.0 V	2.3	-	2.3	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}					
		I_O = 100 µA; $V_{CC(A)} = V_{CC(B)}$ = 0.8 V to 3.6 V	-	0.1	-	0.1	V
		I_O = 3 mA; $V_{CC(A)} = V_{CC(B)}$ = 1.1 V	-	0.25	-	0.25	V
		I_O = 6 mA; $V_{CC(A)} = V_{CC(B)}$ = 1.4 V	-	0.35	-	0.35	V
		I_O = 8 mA; $V_{CC(A)} = V_{CC(B)}$ = 1.65 V	-	0.45	-	0.45	V
		I_O = 9 mA; $V_{CC(A)} = V_{CC(B)}$ = 2.3 V	-	0.55	-	0.55	V
		I_O = 12 mA; $V_{CC(A)} = V_{CC(B)}$ = 3.0 V	-	0.7	-	0.7	V
I_I	input leakage current	$\overline{OE}$ input; V_I = 0 V or 3.6 V; $V_{CC(A)} = V_{CC(B)}$ = 0.8 V to 3.6 V	-	±1	-	±5	µA
I_{OZ}	OFF-state output current	A or B port; V_O = 0 V or V_{CCO}; $V_{CC(A)} = V_{CC(B)}$ = 3.6 V	-	±5	-	±30	µA
		suspend mode A port; V_O = 0 V or V_{CCO}; $V_{CC(A)}$ = 3.6 V; $V_{CC(B)}$ = 0 V	-	±5	-	±30	µA
		suspend mode B port; V_O = 0 V or V_{CCO}; $V_{CC(A)}$ = 0 V; $V_{CC(B)}$ = 3.6 V	-	±5	-	±30	µA

Symbol	Parameter	Conditions	-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Max	Min	Max	
I_{OFF}	power-off leakage current	A port; V_I or V_O = 0 V to 3.6 V; $V_{CC(A)}$ = 0 V; $V_{CC(B)}$ = 0.8 V to 3.6 V	-	±5	-	±30	μA
		B port; V_I or V_O = 0 V to 3.6 V; $V_{CC(B)}$ = 0 V; $V_{CC(A)}$ = 0.8 V to 3.6 V	-	±5	-	±30	μA
I_{CC}	supply current	A port; V_I = 0 V or V_{CCI}; I_O = 0 A					
		$V_{CC(A)}$ = 0.8 V to 3.6 V; $V_{CC(B)}$ = 0.8 V to 3.6 V	-	10	-	55	μA
		$V_{CC(A)}$ = 1.1 V to 3.6 V; $V_{CC(B)}$ = 1.1 V to 3.6 V	-	8	-	50	μA
		$V_{CC(A)}$ = 3.6 V; $V_{CC(B)}$ = 0 V	-	8	-	50	μA
		$V_{CC(A)}$ = 0 V; $V_{CC(B)}$ = 3.6 V	-2	-	-12	-	μA
		B port; V_I = 0 V or V_{CCI}; I_O = 0 A					
		$V_{CC(A)}$ = 0.8 V to 3.6 V; $V_{CC(B)}$ = 0.8 V to 3.6 V	-	10	-	55	μA
		$V_{CC(A)}$ = 1.1 V to 3.6 V; $V_{CC(B)}$ = 1.1 V to 3.6 V	-	8	-	50	μA
		$V_{CC(A)}$ = 3.6 V; $V_{CC(B)}$ = 0 V	-2	-	-12	-	μA
		$V_{CC(A)}$ = 0 V; $V_{CC(B)}$ = 3.6 V	-	8	-	50	μA
		A plus B port ($I_{CC(A)} + I_{CC(B)}$); I_O = 0 A; V_I = 0 V or V_{CCI}; $V_{CC(A)}$ = 0.8 V to 3.6 V; $V_{CC(B)}$ = 0.8 V to 3.6 V	-	20	-	70	μA
		A plus B port ($I_{CC(A)} + I_{CC(B)}$); I_O = 0 A; V_I = 0 V or V_{CCI}; $V_{CC(A)}$ = 1.1 V to 3.6 V; $V_{CC(B)}$ = 1.1 V to 3.6 V	-	16	-	65	μA
ΔI_{CC}	additional supply current	V_I = 3.0 V; $V_{CC(A)} = V_{CC(B)}$ = 3.6 V	-	500	-	650	μA

[1] V_{CCO} is the supply voltage associated with the output port.
[2] V_{CCI} is the supply voltage associated with the data input port.

Table 9. Typical total supply current ($I_{CC(A)} + I_{CC(B)}$)

$V_{CC(A)}$	$V_{CC(B)}$							Unit
	0 V	0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
0 V	0	0.1	0.1	0.1	0.1	0.1	0.1	μA
0.8 V	0.1	0.1	0.1	0.1	0.1	0.3	1.6	μA
1.2 V	0.1	0.1	0.1	0.1	0.1	0.1	0.8	μA
1.5 V	0.1	0.1	0.1	0.1	0.1	0.1	0.4	μA
1.8 V	0.1	0.1	0.1	0.1	0.1	0.1	0.2	μA
2.5 V	0.1	0.3	0.1	0.1	0.1	0.1	0.1	μA
3.3 V	0.1	1.6	0.8	0.4	0.2	0.1	0.1	μA

11. Dynamic characteristics

Table 10. Typical power dissipation capacitance at $V_{CC(A)} = V_{CC(B)}$ and T_{amb} = 25 °C [1][2]

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	$V_{CC(A)} = V_{CC(B)}$						Unit
			0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
C_{PD}	power dissipation capacitance	inputs An, B4	0.2	0.2	0.2	0.2	0.3	0.5	pF
		outputs YBn, YA4	9.3	9.5	9.6	9.7	9.9	11.2	pF

[1] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:
f_i = input frequency in MHz;
f_o = output frequency in MHz;
C_L = load capacitance in pF;
V_{CC} = supply voltage in V;
N = number of inputs switching;
$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

[2] f_i = 10 MHz; V_I = GND to V_{CC}; $t_r = t_f$ = 1 ns; C_L = 0 pF; $R_L = \infty\ \Omega$.

Table 11. Typical dynamic characteristics at $V_{CC(A)}$ = 0.8 V and T_{amb} = 25 °C [1]

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 5; for wave forms see Fig. 3 and Fig. 4

Symbol	Parameter	Conditions	$V_{CC(B)}$						Unit
			0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
t_{pd}	propagation delay	An to YBn	14.5	7.3	6.5	6.2	5.9	6.0	ns
		B4 to YA4	14.5	12.7	12.4	12.3	12.1	12.0	ns
t_{dis}	disable time	$\overline{OE}$ to YBn	14.3	14.3	14.3	14.3	14.3	14.3	ns
		$\overline{OE}$ to YA4	17.0	9.9	9.0	9.4	9.0	9.7	ns
t_{en}	enable time	$\overline{OE}$ to YBn	18.2	18.2	18.2	18.2	18.2	18.2	ns
		$\overline{OE}$ to YA4	19.2	10.7	9.8	9.6	9.7	10.2	ns

[1] t_{pd} is the same as t_{PLH} and t_{PHL}; t_{dis} is the same as t_{PLZ} and t_{PHZ}; t_{en} is the same as t_{PZL} and t_{PZH}.

Table 12. Typical dynamic characteristics at $V_{CC(B)}$ = 0.8 V and T_{amb} = 25 °C [1]

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 5; for wave forms see Fig. 3 and Fig. 4

Symbol	Parameter	Conditions	$V_{CC(A)}$						Unit
			0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
t_{pd}	propagation delay	An to YBn	14.5	12.7	12.4	12.3	12.1	12.0	ns
		B4 to YA4	14.5	7.3	6.5	6.2	5.9	6.0	ns
t_{dis}	disable time	$\overline{OE}$ to YBn	14.3	5.5	4.1	4.0	3.0	3.5	ns
		$\overline{OE}$ to YA4	17.0	13.8	13.4	13.1	12.9	12.7	ns
t_{en}	enable time	$\overline{OE}$ to YBn	18.2	5.6	4.0	3.2	2.4	2.2	ns
		$\overline{OE}$ to YA4	19.2	14.6	14.1	13.9	13.7	13.6	ns

[1] t_{pd} is the same as t_{PLH} and t_{PHL}; t_{dis} is the same as t_{PLZ} and t_{PHZ}; t_{en} is the same as t_{PZL} and t_{PZH}.

Table 13. Dynamic characteristics for temperature range -40 °C to +85 °C [1]

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 5; for wave forms see Fig. 3 and Fig. 4

Symbol	Parameter	Conditions	$V_{CC(B)}$										Unit
			1.2 V ±0.1 V		1.5 V ±0.1 V		1.8 V ±0.15 V		2.5 V ±0.2 V		3.3 V ±0.3 V		
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
$V_{CC(A)}$ = 1.1 V to 1.3 V													
t_{pd}	propagation delay	An to YBn	2.0	10.5	1.3	7.8	1.2	6.9	1.0	5.9	0.8	5.7	ns
		B4 to YA4	2.0	10.5	1.5	9.9	1.5	9.7	1.4	9.4	1.4	9.3	ns
t_{dis}	disable time	$\overline{OE}$ to YBn	2.0	10.0	2.0	10.0	2.0	10.0	2.0	10.0	2.0	10.0	ns
		$\overline{OE}$ to YA4	2.0	11.1	2.0	8.6	1.0	8.0	0.7	7.0	1.0	8.0	ns
t_{en}	enable time	$\overline{OE}$ to YBn	2.0	13.5	2.0	13.5	2.0	13.5	2.0	13.5	2.0	13.5	ns
		$\overline{OE}$ to YA4	2.0	15.0	2.0	11.0	2.0	9.4	1.0	7.8	1.0	7.4	ns
$V_{CC(A)}$ = 1.4 V to 1.6 V													
t_{pd}	propagation delay	An to YBn	1.5	9.9	1.0	7.1	1.0	6.0	0.5	4.8	0.5	4.3	ns
		B4 to YA4	1.3	7.8	1.0	7.1	0.9	6.9	0.8	6.6	0.6	6.5	ns
t_{dis}	disable time	$\overline{OE}$ to YBn	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	ns
		$\overline{OE}$ to YA4	2.0	10.2	1.5	7.5	0.9	7.2	0.4	6.2	0.4	6.1	ns
t_{en}	enable time	$\overline{OE}$ to YBn	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	ns
		$\overline{OE}$ to YA4	2.0	14.4	1.4	7.9	1.3	7.7	1.1	6.4	1.1	5.6	ns
$V_{CC(A)}$ = 1.65 V to 1.95 V													
t_{pd}	propagation delay	An to YBn	1.5	9.7	0.9	6.9	0.8	5.7	0.5	4.5	0.3	4.0	ns
		B4 to YA4	1.2	6.9	1.0	6.0	0.8	5.7	0.5	5.5	0.5	5.3	ns
t_{dis}	disable time	$\overline{OE}$ to YBn	0.5	5.7	0.5	5.7	0.5	5.7	0.5	5.7	0.5	5.7	ns
		$\overline{OE}$ to YA4	2.0	9.9	1.5	7.0	0.8	6.9	0.2	5.8	0.2	5.9	ns
t_{en}	enable time	$\overline{OE}$ to YBn	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	ns
		$\overline{OE}$ to YA4	1.5	13.9	1.2	7.2	1.2	6.9	0.8	5.4	0.6	5.0	ns
$V_{CC(A)}$ = 2.3 V to 2.7 V													
t_{pd}	propagation delay	An to YBn	1.4	9.4	0.8	6.6	0.5	5.5	0.4	4.2	0.2	3.7	ns
		B4 to YA4	1.0	5.9	0.5	4.8	0.5	4.5	0.4	4.2	0.3	3.9	ns
t_{dis}	disable time	$\overline{OE}$ to YBn	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	ns
		$\overline{OE}$ to YA4	2.0	9.3	1.5	6.7	0.7	6.3	0.2	5.0	0.2	5.7	ns
t_{en}	enable time	$\overline{OE}$ to YBn	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	ns
		$\overline{OE}$ to YA4	1.5	13.6	1.0	6.8	1.0	6.0	0.8	4.6	0.6	4.2	ns
$V_{CC(A)}$ = 3.0 V to 3.6 V													
t_{pd}	propagation delay	An to YBn	1.4	9.3	0.6	6.5	0.5	5.3	0.3	3.9	0.2	3.5	ns
		B4 to YA4	0.8	5.7	0.5	4.3	0.3	4.0	0.2	3.7	0.2	3.5	ns
t_{dis}	disable time	$\overline{OE}$ to YBn	0.2	4.5	0.2	4.5	0.2	4.5	0.2	4.5	0.2	4.5	ns
		$\overline{OE}$ to YA4	2.0	9.0	1.5	6.4	0.7	6.1	0.2	4.8	0.2	5.6	ns
t_{en}	enable time	$\overline{OE}$ to YBn	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	ns
		$\overline{OE}$ to YA4	1.5	13.4	1.0	6.7	1.0	5.9	0.7	4.4	0.5	4.0	ns

[1] t_{pd} is the same as t_{PLH} and t_{PHL}; t_{dis} is the same as t_{PLZ} and t_{PHZ}; t_{en} is the same as t_{PZL} and t_{PZH}.

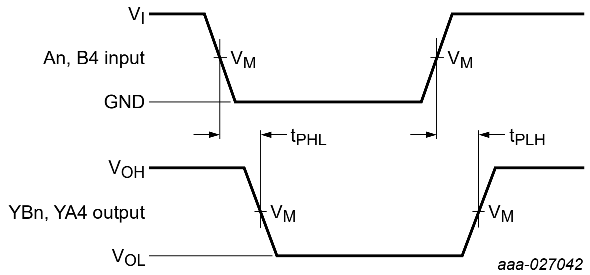
Table 14. Dynamic characteristics for temperature range -40 °C to +125 °C [1]

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 5; for wave forms see Fig. 3 and Fig. 4

Symbol	Parameter	Conditions	$V_{CC(B)}$										Unit
			1.2 V ±0.1 V		1.5 V ±0.1 V		1.8 V ±0.15 V		2.5 V ±0.2 V		3.3 V ±0.3 V		
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
$V_{CC(A)}$ = 1.1 V to 1.3 V													
t_{pd}	propagation delay	An to YBn	2.0	12.1	1.3	9.0	1.2	8.0	1.0	6.8	0.8	6.6	ns
		B4 to YA4	2.0	12.1	1.5	11.4	1.5	11.2	1.4	10.9	1.4	10.7	ns
t_{dis}	disable time	$\overline{OE}$ to YBn	2.0	11.5	2.0	11.5	2.0	11.5	2.0	11.5	2.0	11.5	ns
		$\overline{OE}$ to YA4	2.0	12.8	2.0	9.9	1.0	9.2	0.7	8.1	1.0	9.2	ns
t_{en}	enable time	$\overline{OE}$ to YBn	2.0	15.6	2.0	15.6	2.0	15.6	2.0	15.6	2.0	15.6	ns
		$\overline{OE}$ to YA4	2.0	17.3	2.0	12.7	2.0	10.9	1.0	9.0	1.0	8.6	ns
$V_{CC(A)}$ = 1.4 V to 1.6 V													
t_{pd}	propagation delay	An to YBn	1.5	11.4	1.0	8.2	1.0	6.9	0.5	5.6	0.5	5.0	ns
		B4 to YA4	1.3	9.0	1.0	8.2	0.9	8.0	0.8	7.6	0.6	7.5	ns
t_{dis}	disable time	$\overline{OE}$ to YBn	1.0	6.9	1.0	6.9	1.0	6.9	1.0	6.9	1.0	6.9	ns
		$\overline{OE}$ to YA4	2.0	11.8	1.5	8.7	0.9	8.3	0.4	7.2	0.4	7.1	ns
t_{en}	enable time	$\overline{OE}$ to YBn	1.0	8.7	1.0	8.7	1.0	8.7	1.0	8.7	1.0	8.7	ns
		$\overline{OE}$ to YA4	2.0	16.6	1.4	9.1	1.3	8.9	1.1	7.4	1.1	6.5	ns
$V_{CC(A)}$ = 1.65 V to 1.95 V													
t_{pd}	propagation delay	An to YBn	1.5	11.2	0.9	8.0	0.8	6.6	0.5	5.2	0.3	4.6	ns
		B4 to YA4	1.2	8.0	1.0	6.9	0.8	6.6	0.5	6.4	0.5	6.1	ns
t_{dis}	disable time	$\overline{OE}$ to YBn	0.5	6.6	0.5	6.6	0.5	6.6	0.5	6.6	0.5	6.6	ns
		$\overline{OE}$ to YA4	2.0	11.4	1.5	8.1	0.8	8.0	0.2	6.7	0.2	6.8	ns
t_{en}	enable time	$\overline{OE}$ to YBn	1.0	7.8	1.0	7.8	1.0	7.8	1.0	7.8	1.0	7.8	ns
		$\overline{OE}$ to YA4	1.5	16.0	1.2	8.3	1.2	8.0	0.8	6.3	0.6	5.8	ns
$V_{CC(A)}$ = 2.3 V to 2.7 V													
t_{pd}	propagation delay	An to YBn	1.4	10.9	0.8	7.6	0.5	6.4	0.4	4.9	0.2	4.3	ns
		B4 to YA4	1.0	6.8	0.5	5.6	0.5	5.2	0.4	4.9	0.3	4.5	ns
t_{dis}	disable time	$\overline{OE}$ to YBn	0.2	4.6	0.2	4.6	0.2	4.6	0.2	4.6	0.2	4.6	ns
		$\overline{OE}$ to YA4	2.0	10.7	1.5	7.8	0.7	7.3	0.2	5.8	0.2	6.6	ns
t_{en}	enable time	$\overline{OE}$ to YBn	0.6	5.2	0.6	5.2	0.6	5.2	0.6	5.2	0.6	5.2	ns
		$\overline{OE}$ to YA4	1.5	15.7	1.0	7.9	1.0	6.9	0.8	5.3	0.6	4.9	ns
$V_{CC(A)}$ = 3.0 V to 3.6 V													
t_{pd}	propagation delay	An to YBn	1.4	10.7	0.6	7.5	0.5	6.1	0.3	4.5	0.2	4.1	ns
		B4 to YA4	0.8	6.6	0.5	5.0	0.3	4.6	0.2	4.3	0.2	4.1	ns
t_{dis}	disable time	$\overline{OE}$ to YBn	0.2	5.2	0.2	5.2	0.2	5.2	0.2	5.2	0.2	5.2	ns
		$\overline{OE}$ to YA4	2.0	10.4	1.5	7.4	0.7	7.1	0.2	5.6	0.2	6.5	ns
t_{en}	enable time	$\overline{OE}$ to YBn	0.5	4.6	0.5	4.6	0.5	4.6	0.5	4.6	0.5	4.6	ns
		$\overline{OE}$ to YA4	1.5	15.5	1.0	7.8	1.0	6.8	0.7	5.1	0.5	4.6	ns

[1] t_{pd} is the same as t_{PLH} and t_{PHL}; t_{dis} is the same as t_{PLZ} and t_{PHZ}; t_{en} is the same as t_{PZL} and t_{PZH}.

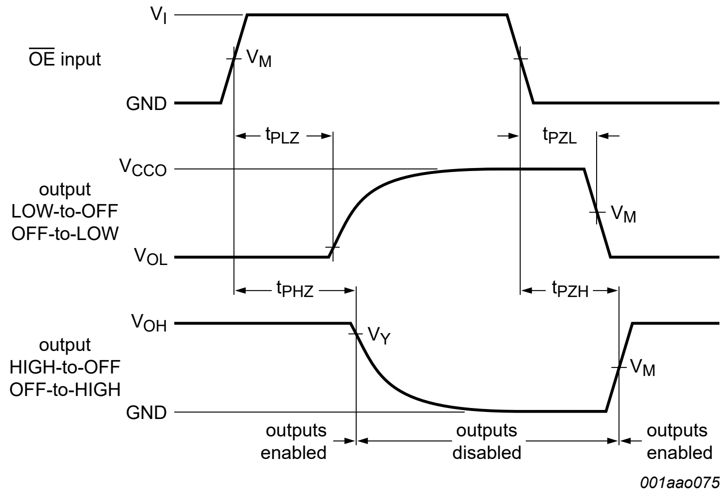
11.1. Waveforms and test circuit



Measurement points are given in Table 15.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 3. The data input (An, B4) to output (YBn, YA4) propagation delay times



Measurement points are given in Table 15.

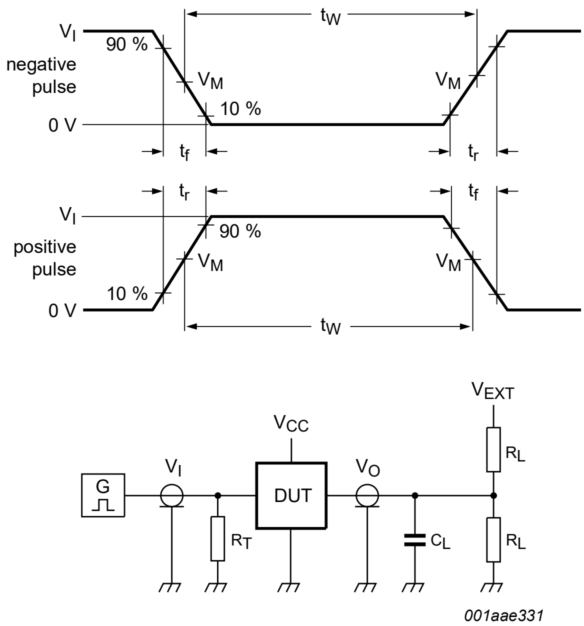
V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 4. Enable and disable times

Table 15. Measurement points

Supply voltage	Input[1]	Output[2]		
$V_{CC(A)}$, $V_{CC(B)}$	V_M	V_M	V_X	V_Y
0.8 V to 1.6 V	$0.5V_{CCI}$	$0.5V_{CCO}$	V_{OL} + 0.1 V	V_{OH} - 0.1 V
1.65 V to 2.7 V	$0.5V_{CCI}$	$0.5V_{CCO}$	V_{OL} + 0.15 V	V_{OH} - 0.15 V
3.0 V to 3.6 V	$0.5V_{CCI}$	$0.5V_{CCO}$	V_{OL} + 0.3 V	V_{OH} - 0.3 V

[1] V_{CCI} is the supply voltage associated with the data input port.
[2] V_{CCO} is the supply voltage associated with the output port.



Test data is given in Table 16 .

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance.

V_{EXT} = External voltage for measuring switching times.

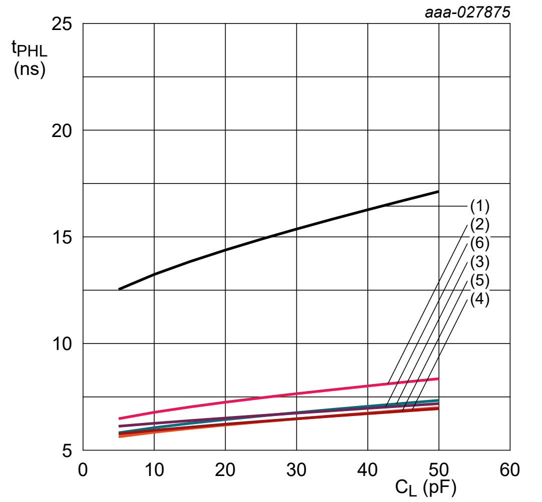
Fig. 5. Test circuit for measuring switching times

Table 16. Test data

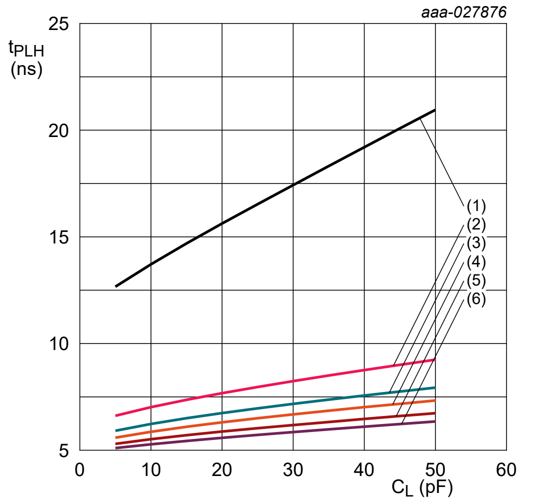
Supply voltage	Input		Load		V_{EXT}		
$V_{CC(A)}$, $V_{CC(B)}$	V_I[1]	Δt/ΔV[2]	C_L	R_L	t_{PLH}, t_{PHL}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}[3]
0.8 V to 1.6 V	V_{CCI}	≤ 1.0 ns/V	15 pF	2 kΩ	open	GND	$2V_{CCO}$
1.65 V to 2.7 V	V_{CCI}	≤ 1.0 ns/V	15 pF	2 kΩ	open	GND	$2V_{CCO}$
3.0 V to 3.6 V	V_{CCI}	≤ 1.0 ns/V	15 pF	2 kΩ	open	GND	$2V_{CCO}$

[1] V_{CCI} is the supply voltage associated with the data input port.
[2] dV/dt ≥ 1.0 V/ns
[3] V_{CCO} is the supply voltage associated with the output port.

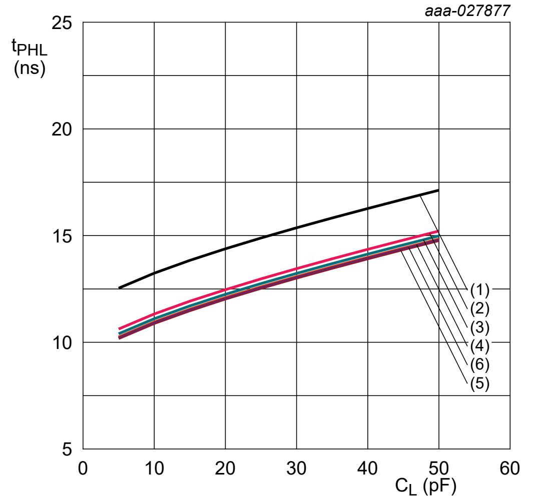
11.2. Typical propagation delay characteristics



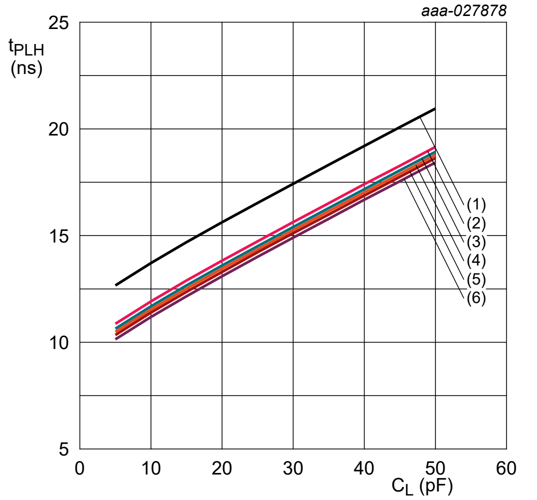
a. HIGH to LOW propagation delay (An to YBn)



b. LOW to HIGH propagation delay (An to YBn)



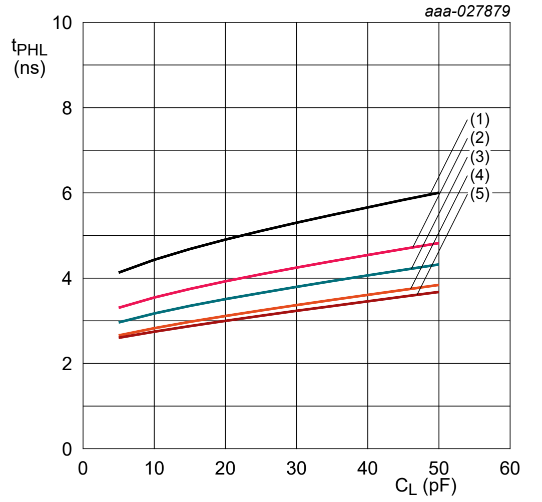
c. HIGH to LOW propagation delay (B4 to YA4)



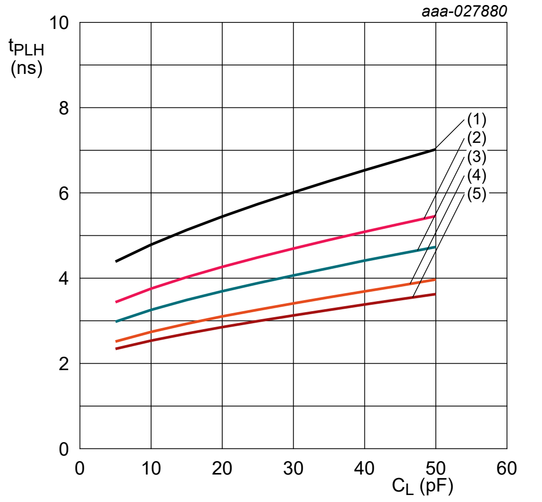
d. LOW to HIGH propagation delay (B4 to YA4)

(1) $V_{CC(B)}$ = 0.8 V
(2) $V_{CC(B)}$ = 1.2 V
(3) $V_{CC(B)}$ = 1.5 V
(4) $V_{CC(B)}$ = 1.8 V
(5) $V_{CC(B)}$ = 2.5 V
(6) $V_{CC(B)}$ = 3.3 V

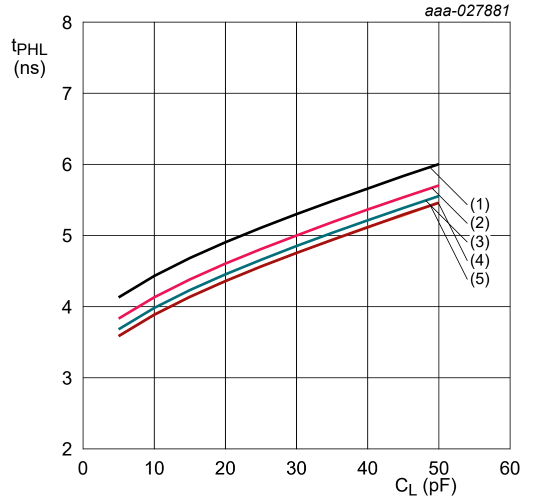
Fig. 6. Typical propagation delay versus load capacitance; T_{amb} = 25 °C; $V_{CC(A)}$ = 0.8 V



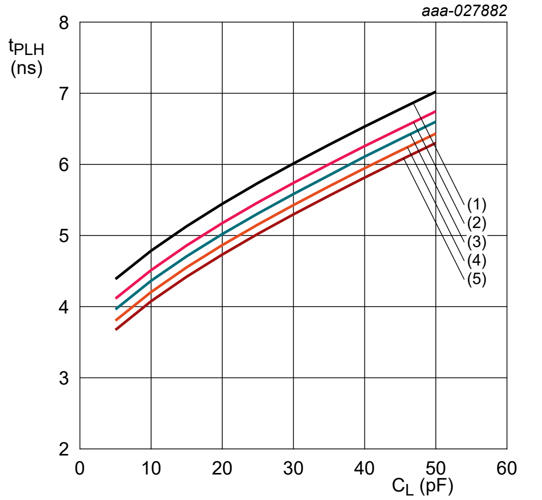
a. HIGH to LOW propagation delay (An to YBn)



b. LOW to HIGH propagation delay (An to YBn)



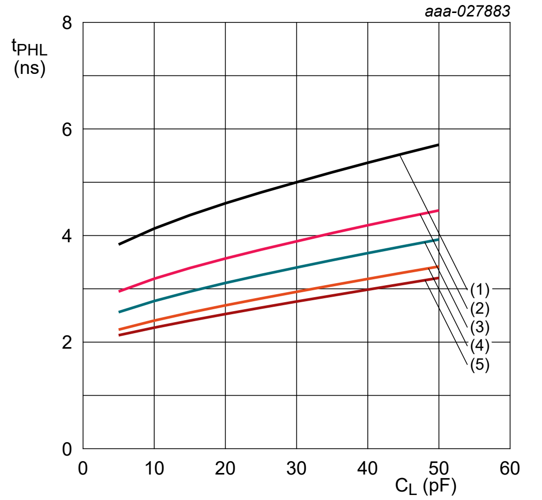
c. HIGH to LOW propagation delay (B4 to YA4)



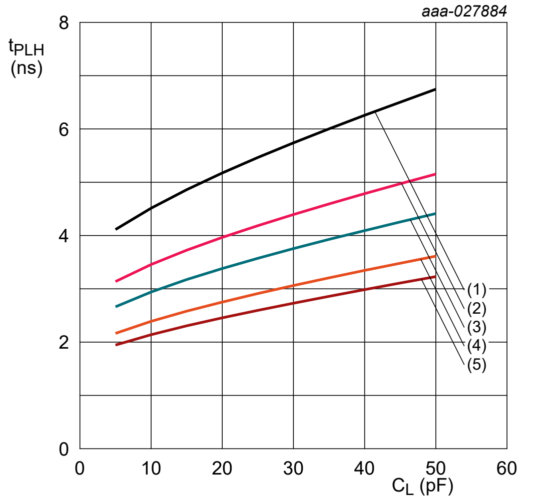
d. LOW to HIGH propagation delay (B4 to YA4)

(1) $V_{CC(B)}$ = 1.2 V
(2) $V_{CC(B)}$ = 1.5 V
(3) $V_{CC(B)}$ = 1.8 V
(4) $V_{CC(B)}$ = 2.5 V
(5) $V_{CC(B)}$ = 3.3 V

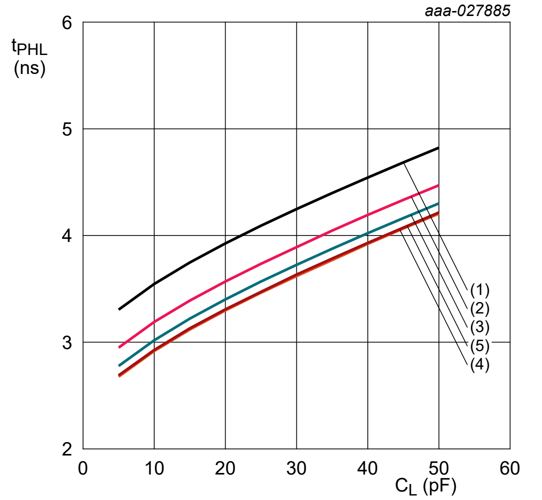
Fig. 7. Typical propagation delay versus load capacitance; T_{amb} = 25 °C; $V_{CC(A)}$ = 1.2 V



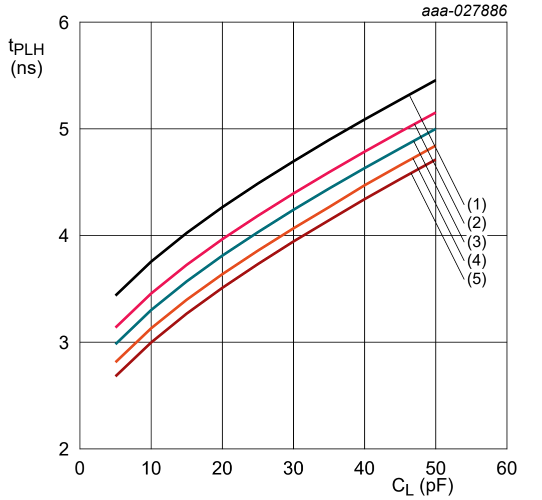
a. HIGH to LOW propagation delay (An to YBn)



b. LOW to HIGH propagation delay (An to YBn)



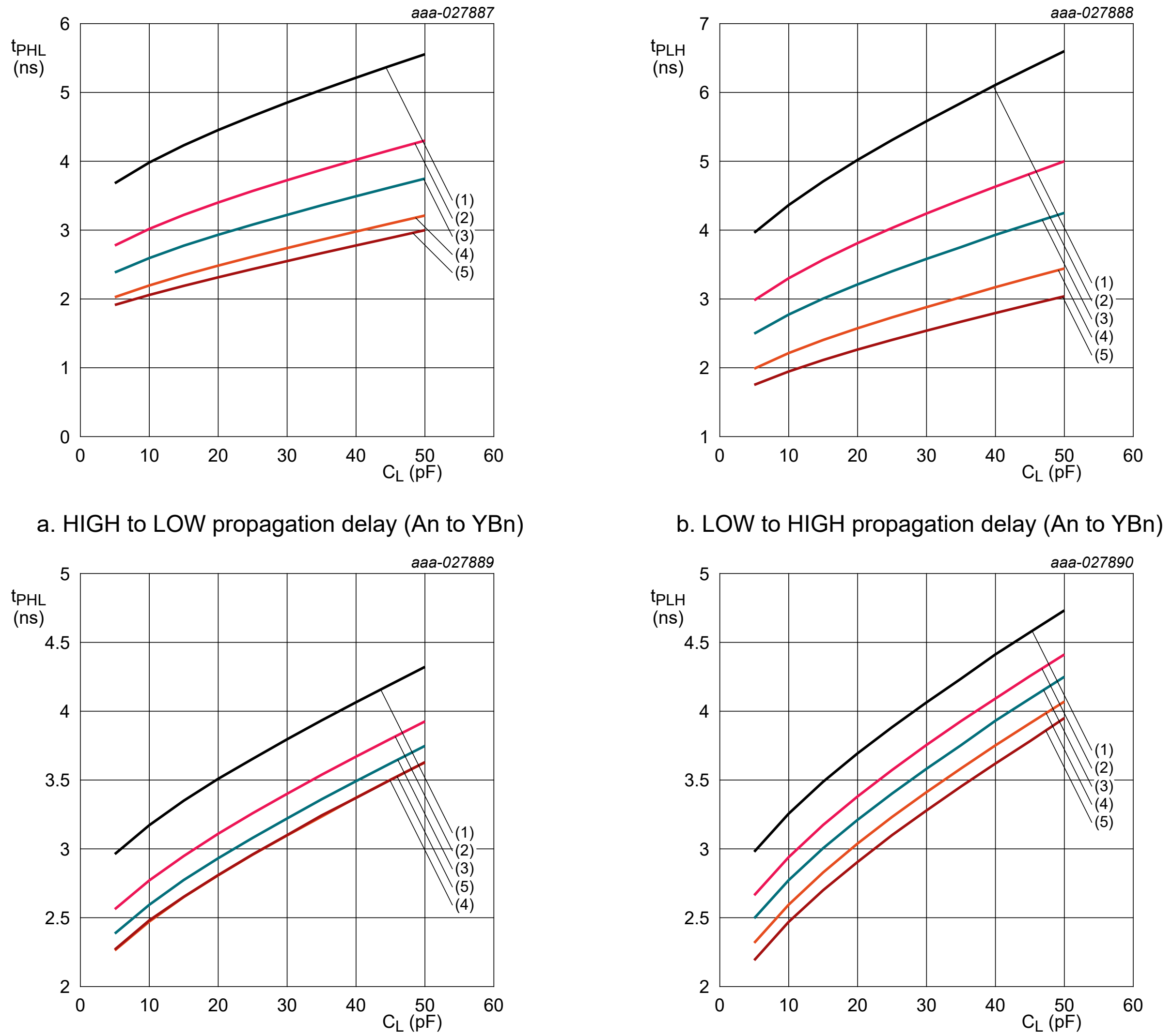
c. HIGH to LOW propagation delay (B4 to YA4)



d. LOW to HIGH propagation delay (B4 to YA4)

(1) $V_{CC(B)}$ = 1.2 V
(2) $V_{CC(B)}$ = 1.5 V
(3) $V_{CC(B)}$ = 1.8 V
(4) $V_{CC(B)}$ = 2.5 V
(5) $V_{CC(B)}$ = 3.3 V

Fig. 8. Typical propagation delay versus load capacitance; T_{amb} = 25 °C; $V_{CC(A)}$ = 1.5 V



a. HIGH to LOW propagation delay (An to YBn)

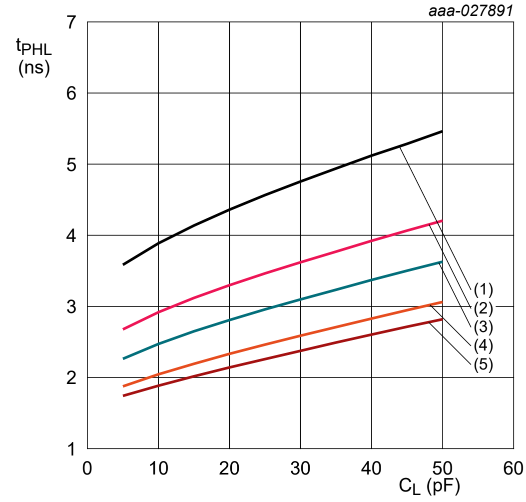
b. LOW to HIGH propagation delay (An to YBn)

c. HIGH to LOW propagation delay (B4 to YA4)

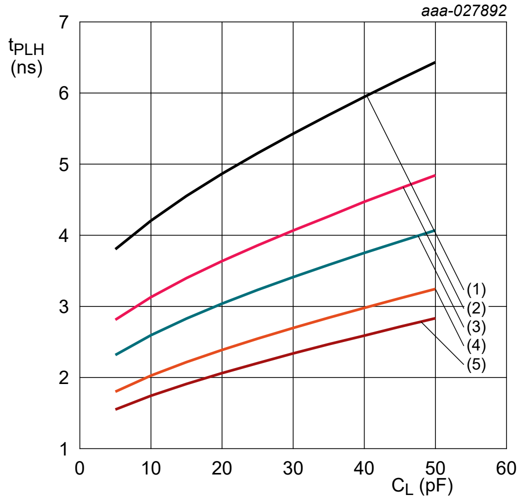
d. LOW to HIGH propagation delay (B4 to YA4)

(1) $V_{CC(B)}$ = 1.2 V
(2) $V_{CC(B)}$ = 1.5 V
(3) $V_{CC(B)}$ = 1.8 V
(4) $V_{CC(B)}$ = 2.5 V
(5) $V_{CC(B)}$ = 3.3 V

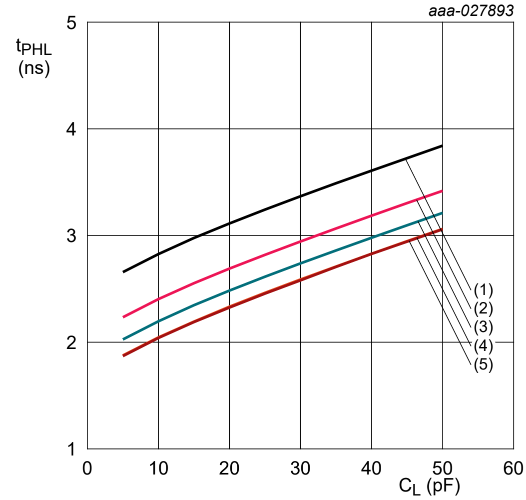
Fig. 9. Typical propagation delay versus load capacitance; T_{amb} = 25 °C; $V_{CC(A)}$ = 1.8 V



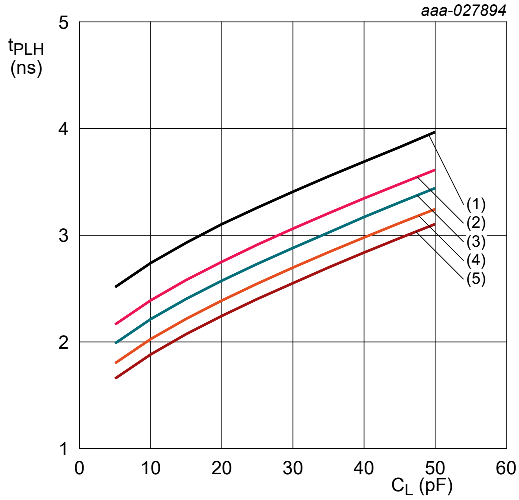
a. HIGH to LOW propagation delay (An to YBn)



b. LOW to HIGH propagation delay (An to YBn)



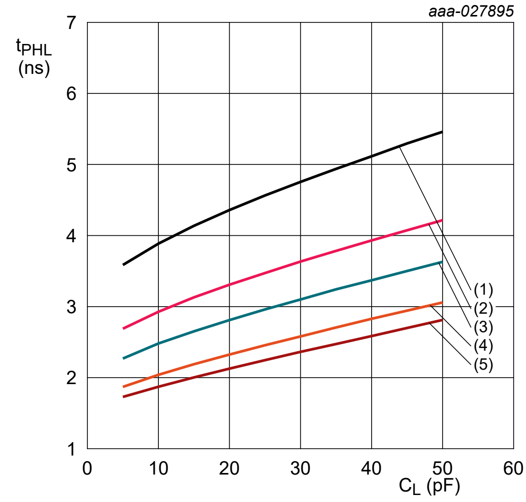
c. HIGH to LOW propagation delay (B4 to YA4)



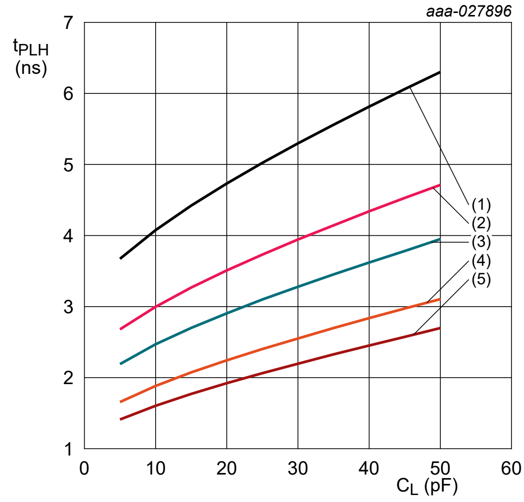
d. LOW to HIGH propagation delay (B4 to YA4)

(1) $V_{CC(B)}$ = 1.2 V
(2) $V_{CC(B)}$ = 1.5 V
(3) $V_{CC(B)}$ = 1.8 V
(4) $V_{CC(B)}$ = 2.5 V
(5) $V_{CC(B)}$ = 3.3 V

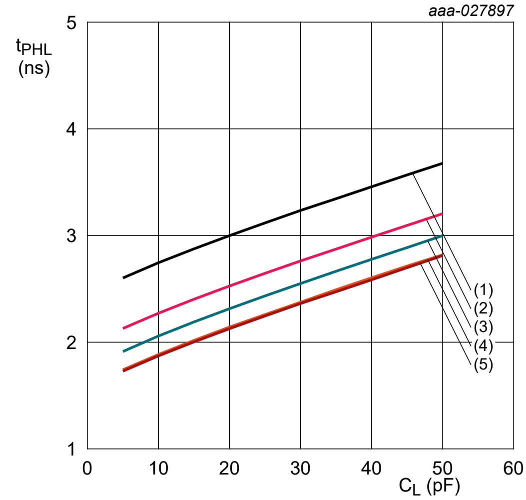
Fig. 10. Typical propagation delay versus load capacitance; T_{amb} = 25 °C; $V_{CC(A)}$ = 2.5 V



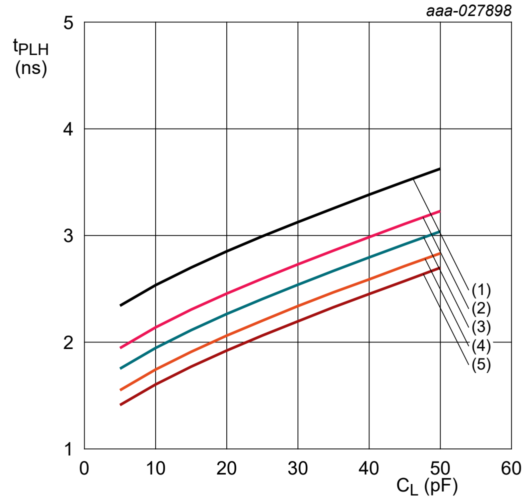
a. HIGH to LOW propagation delay (An to YBn)



b. LOW to HIGH propagation delay (An to YBn)



c. HIGH to LOW propagation delay (B4 to YA4)



d. LOW to HIGH propagation delay (B4 to YA4)

(1) $V_{CC(B)}$ = 1.2 V

(2) $V_{CC(B)}$ = 1.5 V

(3) $V_{CC(B)}$ = 1.8 V

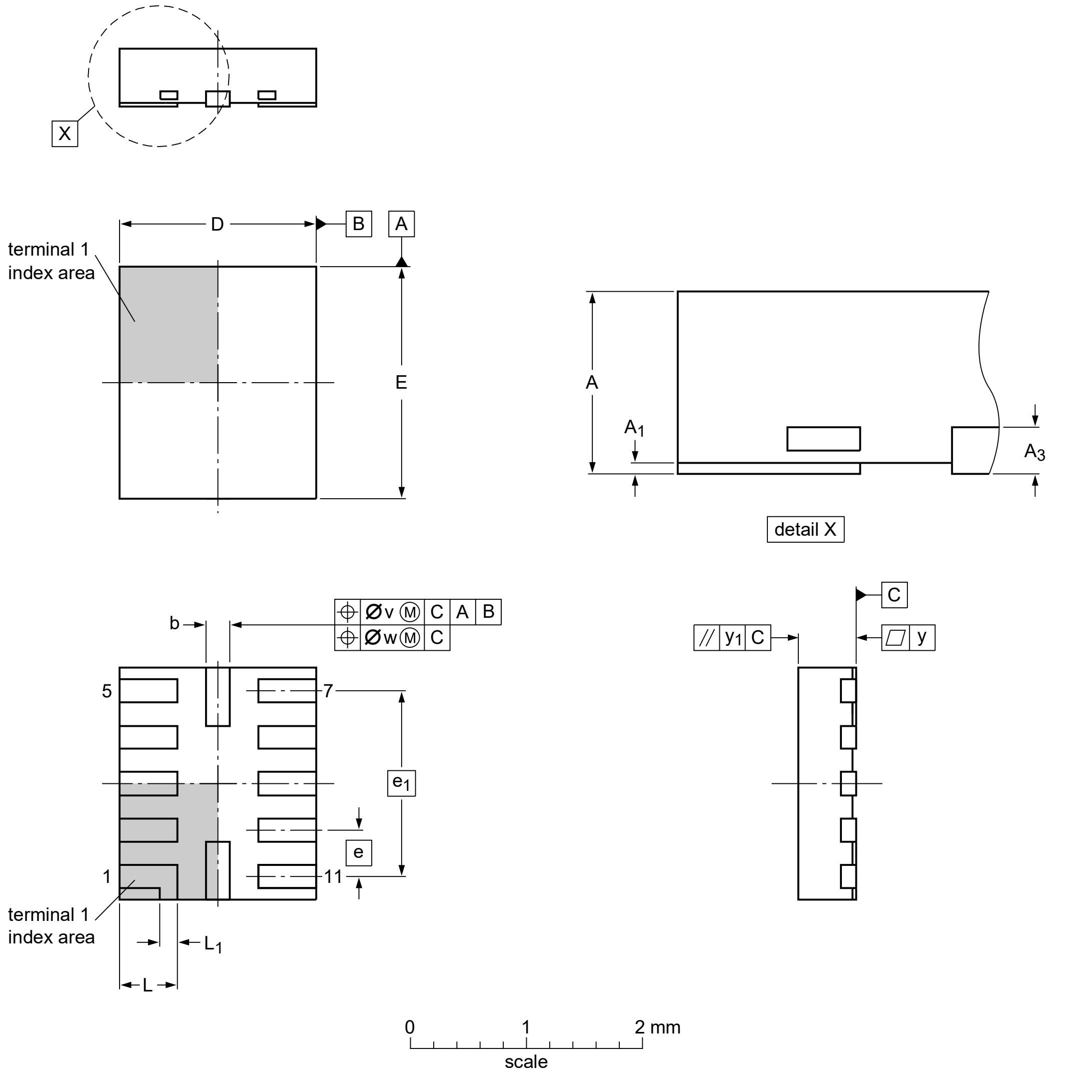
(4) $V_{CC(B)}$ = 2.5 V

(5) $V_{CC(B)}$ = 3.3 V

Fig. 11. Typical propagation delay versus load capacitance; T_{amb} = 25 °C; $V_{CC(A)}$ = 3.3 V

12. Package outline

XQFN12: plastic, extremely thin quad flat package; no leads;
12 terminals; body 1.70 x 2.00 x 0.50 mm **SOT1174-1**



Dimensions

Unit[(1)]		A	A_1	A_3	b	D	E	e	e_1	L	L_1	v	w	y	y_1
	max	0.5	0.05		0.25	1.8	2.1			0.55					
mm	nom			0.127	0.20	1.7	2.0	0.4	1.6	0.50	0.15	0.1	0.05	0.05	0.05
	min		0.00		0.15	1.6	1.9			0.45					

Note
1. Plastic or metal protrusions of 0.075 mm maximum per side are not included.

sot1174-1_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1174-1	- - -	MO-288	- - -			10-04-07 10-04-21

Fig. 12. Package outline SOT1174-1 (XQFN12)

13. Abbreviations

Table 17. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

14. Revision history

Table 18. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AVC4T3144_Q100 v.1	20191115	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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